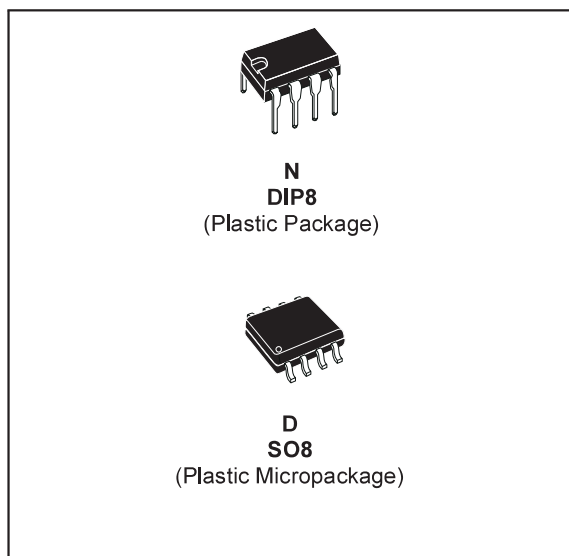




TL081 TL081A - TL081B

GENERAL PURPOSE J-FET SINGLE OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO V_{CC}^+) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : $16V/\mu s$ (typ)

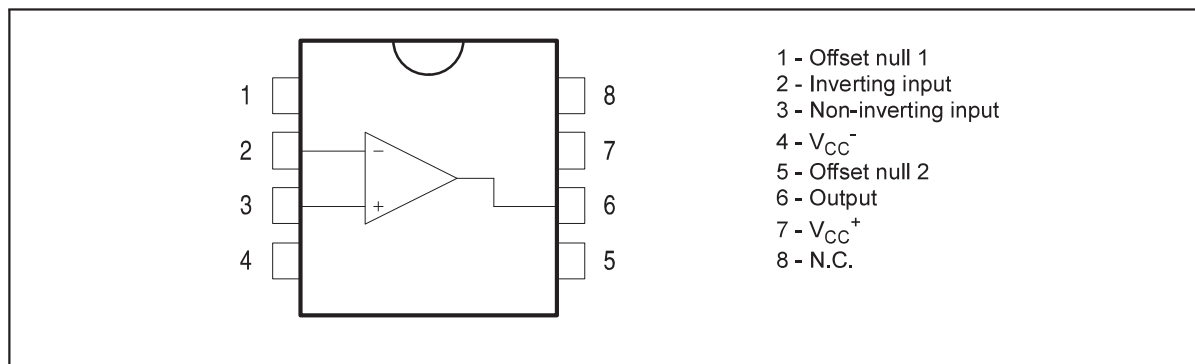


DESCRIPTION

The TL081, TL081A and TL081B are high speed J-FET input single operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

PIN CONNECTIONS (top view)

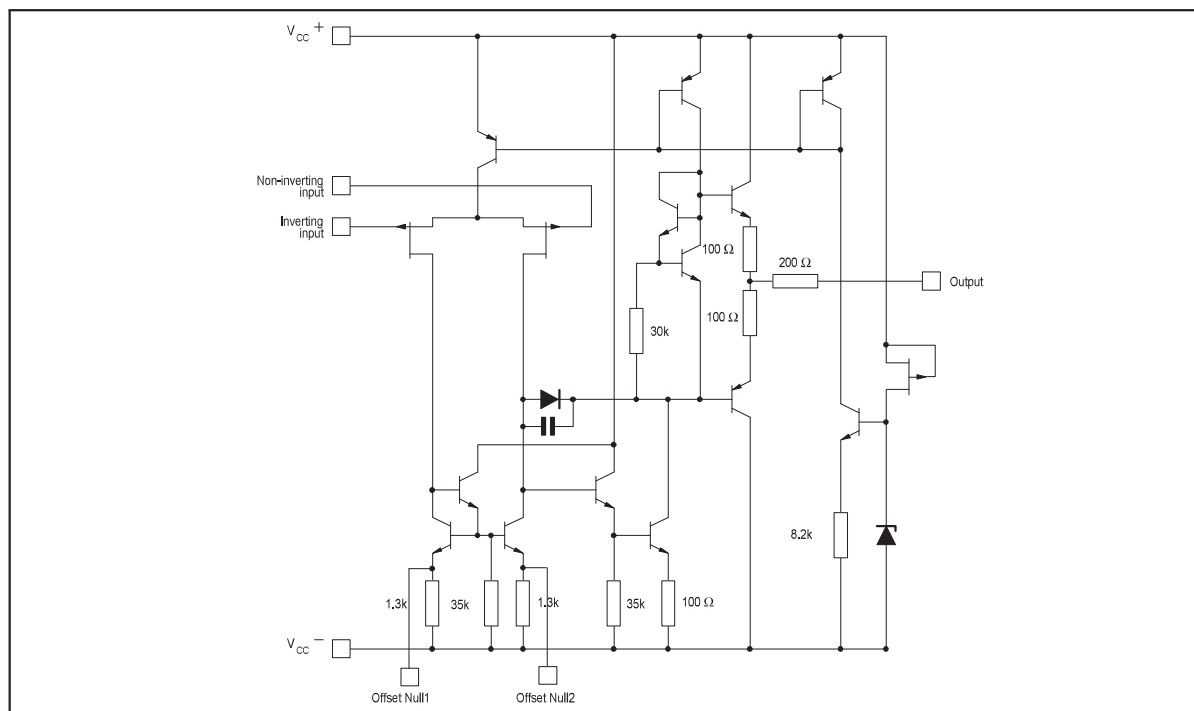


ORDER CODE

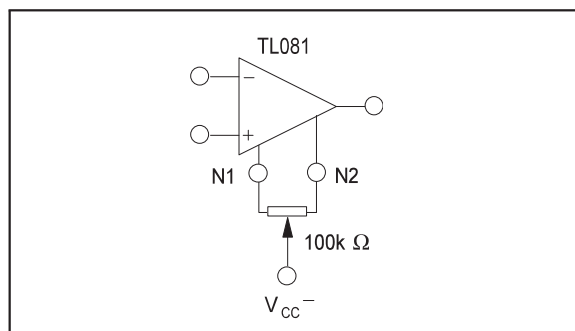
Part Number	Temperature Range	Package	
		N	D
TL081M/AM/BM	-55°C, +125°C	•	•
TL081I/AI/BI	-40°C, +105°C	•	•
TL081C/AC/BC	0°C, +70°C	•	•
Example : TL081CD, TL081IN			

N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

SCHEMATIC DIAGRAM



INPUT OFFSET VOLTAGE NULL CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TL081M, AM, BM	TL081I, AI, BI	TL081C, AC, BC	Unit
V_{CC}	Supply voltage - note ¹⁾	± 18			V
V_i	Input Voltage - note ²⁾	± 15			V
V_{id}	Differential Input Voltage - note ³⁾	± 30			V
P_{tot}	Power Dissipation	680			mW
	Output Short-circuit Duration - note ⁴⁾	Infinite			
T_{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T_{stg}	Storage Temperature Range	-65 to +150			°C

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}^+ and V_{CC}^- .
2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

ELECTRICAL CHARACTERISTICS

$V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	TL081I,M,AC,AI,AM, BC,BI,BM			TL081C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{io}	Input Offset Voltage ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$ TL081 TL081A TL081B TL081 TL081A TL081B		3 3 1	10 6 3 13 7 5		3	10 13	mV
DV_{io}	Input Offset Voltage Drift		10			10		$\mu V/^{\circ}C$
I_{io}	Input Offset Current - note 1) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	100 4		5	100 10	pA nA
I_{ib}	Input Bias Current -note 1 $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20		20	400 20	nA
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega$, $V_o = \pm 10V$) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	80 80	86		70 70	86		dB
I_{CC}	Supply Current, no load $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V_{icm}	Input Common Mode Voltage Range	± 11	+15 -12		± 11	+15 -12		V
CMR	Common Mode Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	80 80	86		70 70	86		dB
I_{os}	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
$\pm V_{opp}$	Output Voltage Swing $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ $R_L = 2k\Omega$ $R_L = 10k\Omega$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ($T_{amb} = +25^{\circ}C$) $V_{in} = 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, unity gain	8	16		8	16		V/ μs
t_r	Rise Time ($T_{amb} = +25^{\circ}C$) $V_{in} = 20mV$, $R_L = 2k\Omega$, $C_L = 100pF$, unity gain		0.1			0.1		μs
K_{ov}	Overshoot ($T_{amb} = +25^{\circ}C$) $V_{in} = 20mV$, $R_L = 2k\Omega$, $C_L = 100pF$, unity gain		10			10		%
GBP	Gain Bandwidth Product ($T_{amb} = +25^{\circ}C$) $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$, $f = 100kHz$	2.5	4		2.5	4		MHz
R_i	Input Resistance		10^{12}			10^{12}		Ω

PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

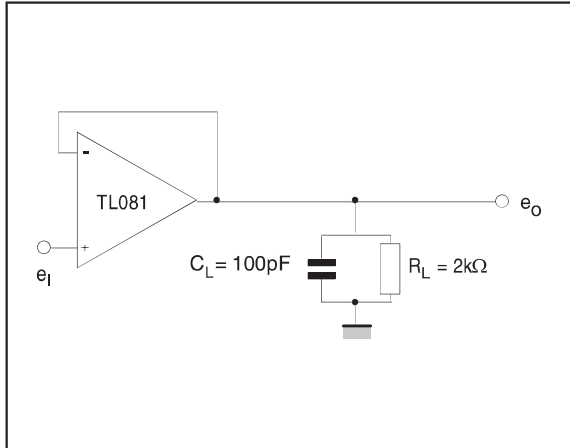
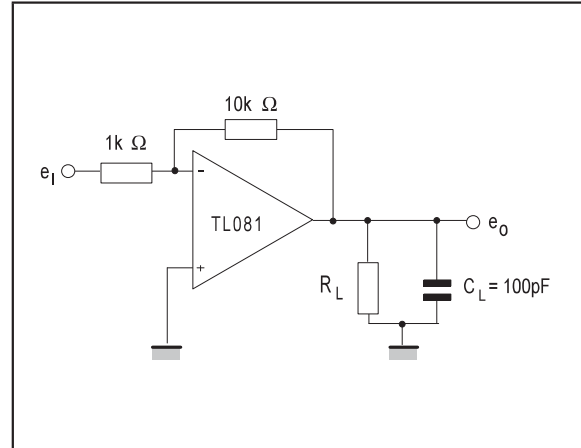
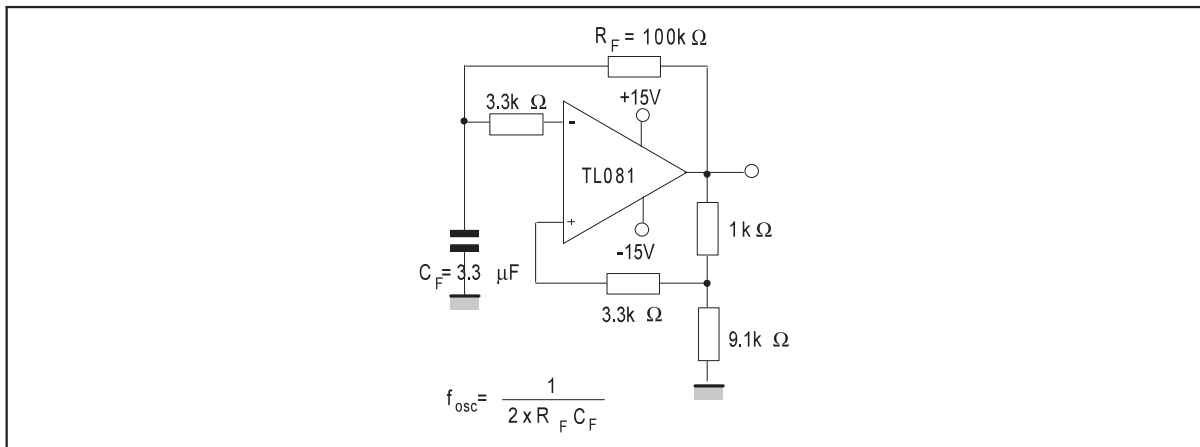


Figure 2 : Gain-of-10 Inverting Amplifier



TYPICAL APPLICATIONS

(0.5Hz) SQUARE WAVE OSCILLATOR



HIGH Q NOTCH FILTER

